

# Development of the muon beam monitor for COMET experiment using SiC detector

## COMET Experiment

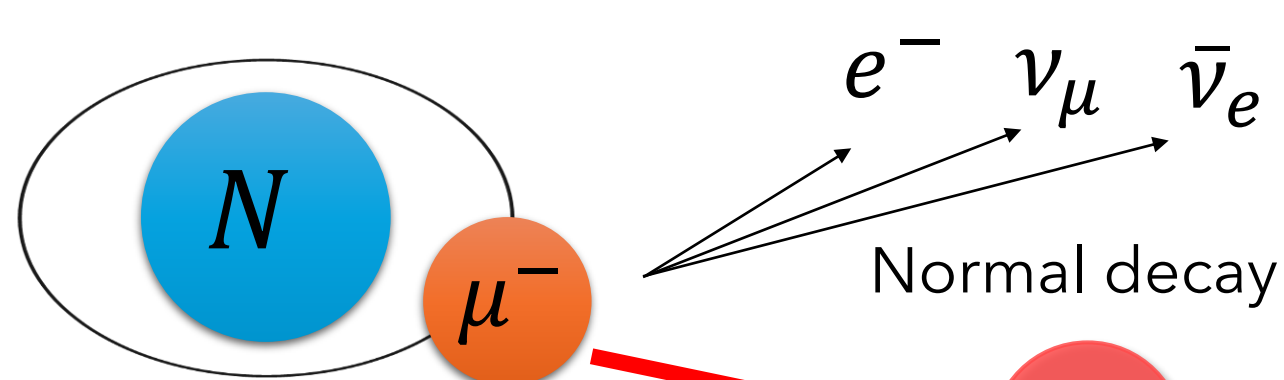
### - COherent Muon to Electron Transition

- Search for  $\mu$ -e conversion process at J-PARC Hadron Facility
- Establishing a new COMET beamline and conducting exploration using pulsed muon beam
- Experiment will be conducted in two stages, Phase-I & II

Target Experiment Sensitivity (Single event sensitivity) Phase-I  $\mathcal{O}(10^{-15})$  Phase-II  $\mathcal{O}(10^{-17})$

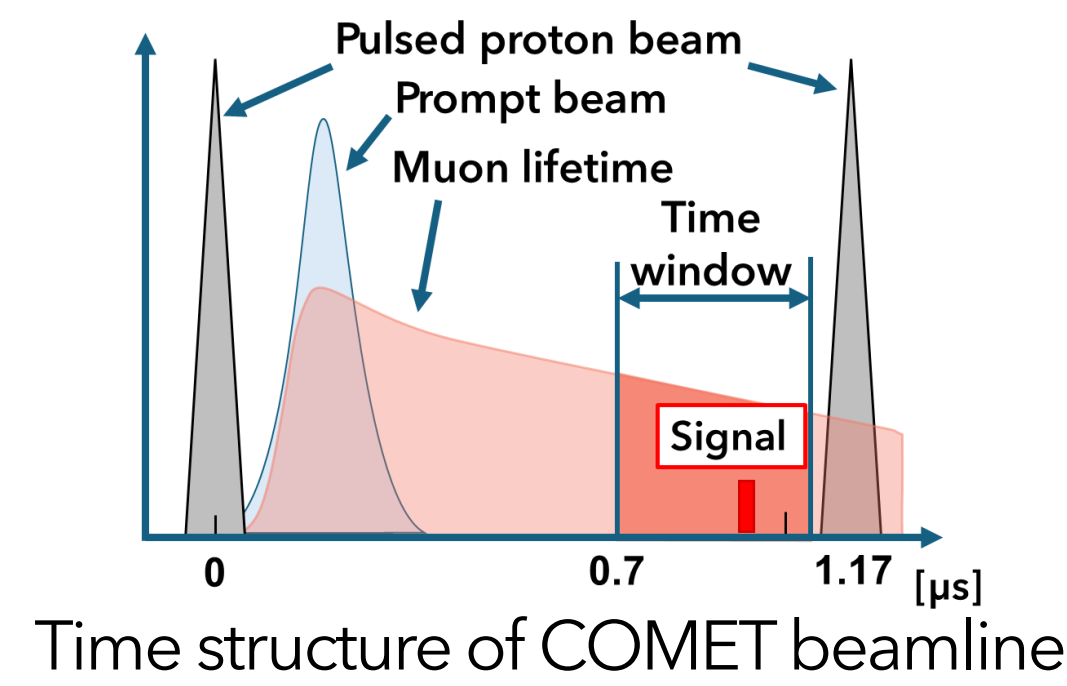
### $\mu$ -e conversion

One of the processes that violates the law of charged lepton flavor conservation.

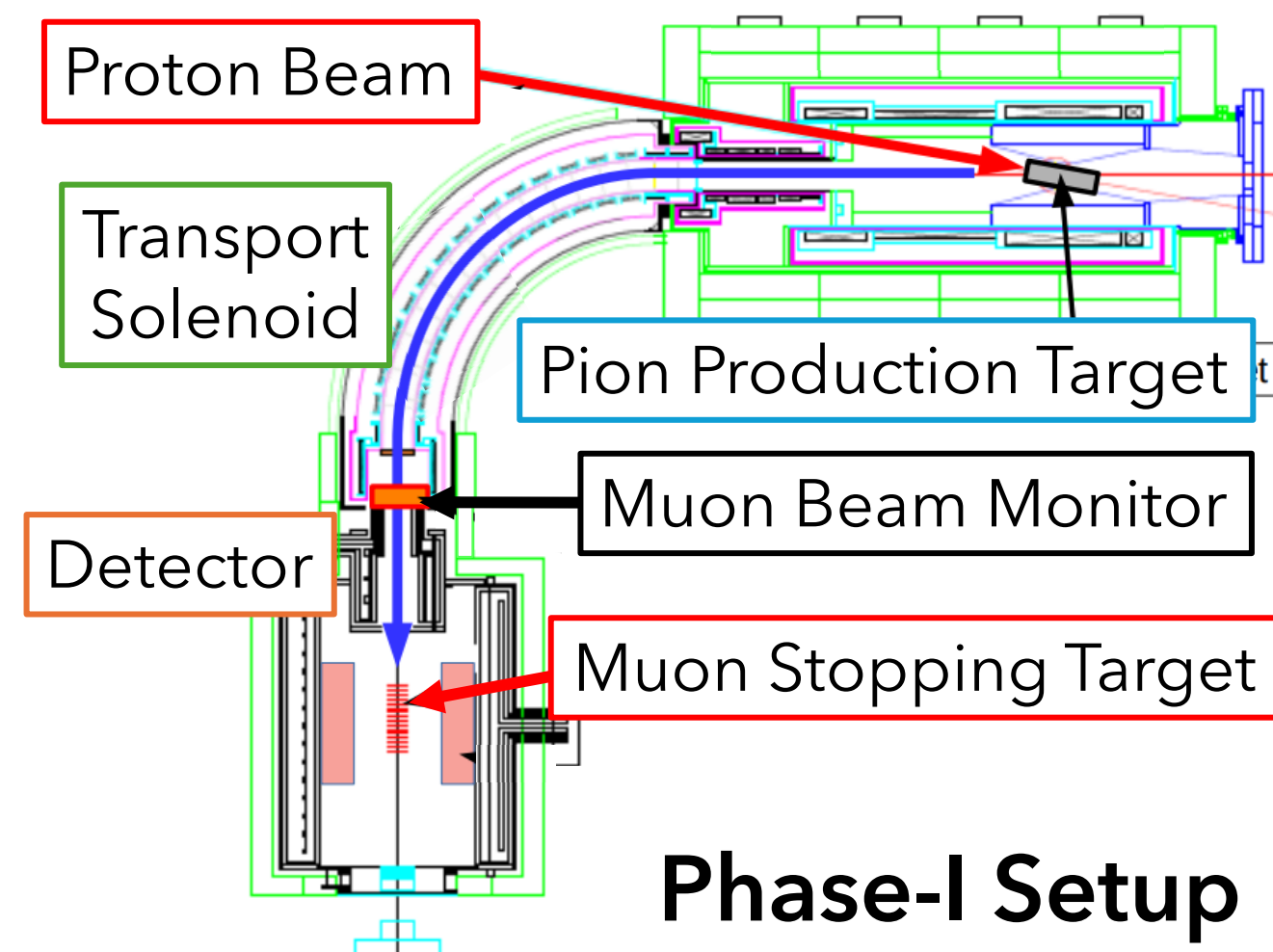


**Directly convert to an electron !**

Standard Model+ Neutrino mass  $\rightarrow BR \sim \mathcal{O}(10^{-54})$   
Beyond the Standard Model  $\rightarrow BR \sim \mathcal{O}(10^{-15})$



**Previous Experiment (SINDRUM-II)**  
Upper Limit of Branching Ratio  $7.0 \times 10^{-13}$  [1]

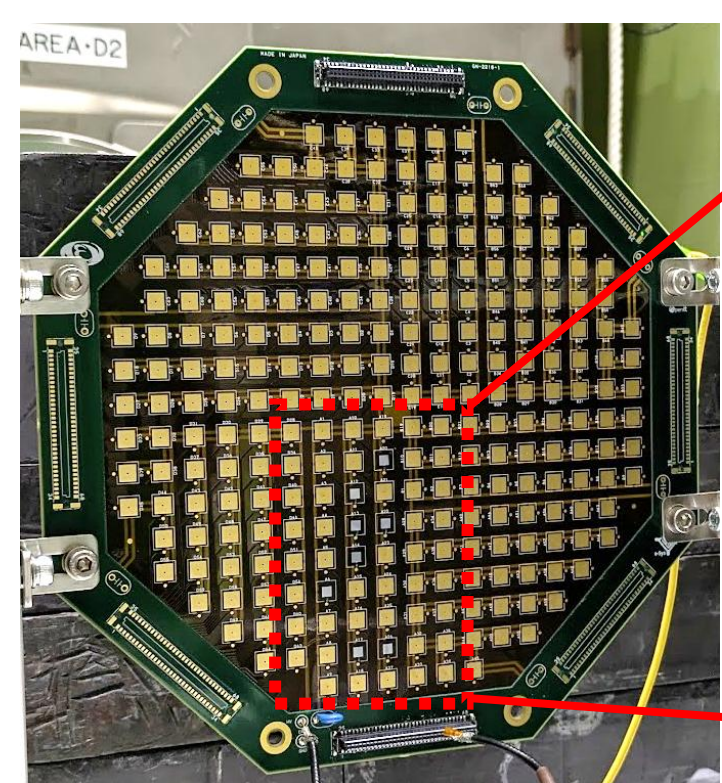


## SiC Muon Beam Monitor

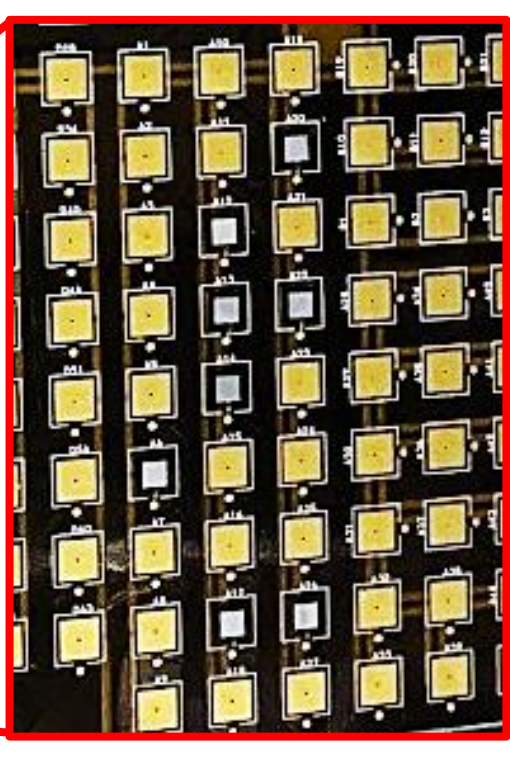
### Muon Beam Monitor

**Objects:** Measure the intensity and stability of the muon beam.

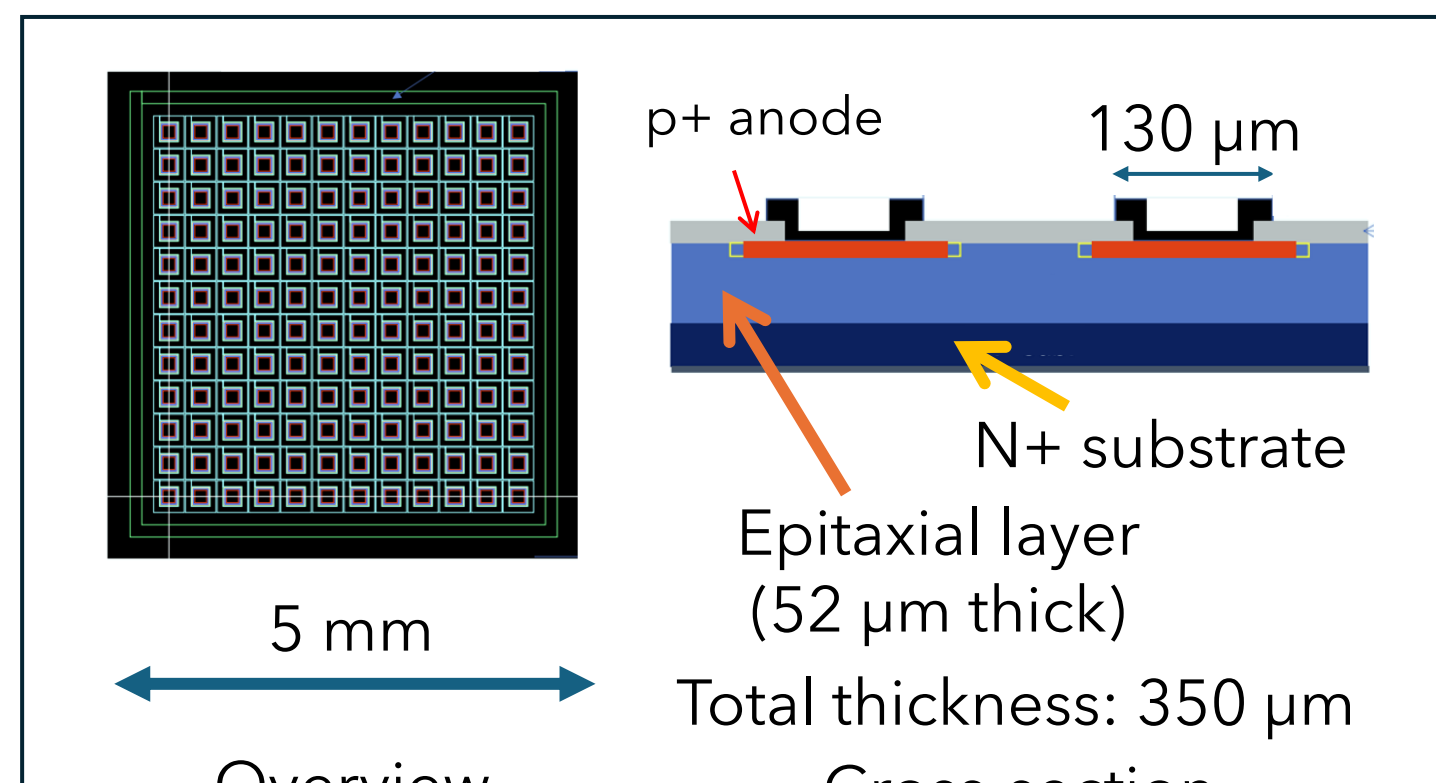
**Detector:** Made of silicon carbide (SiC) and jointly developed by KEK and AIST [2].



Muon beam monitor board



SiC detector (Silvery chips)



Structure of SiC detector

### Why use SiC ?

Muon beam monitor will be directly exposed to a high-intensity muon beam.  
→ Resulting in  $1.6 \times 10^{13} n_{1\text{MeV}} / \text{cm}^2$  and 1.2 MGy.

**Higher Radiation tolerance is required than standard n-type silicon sensor !**

Wide bandgap semiconductors have high radiation tolerance.

→ **SiC is an optimal choice !**

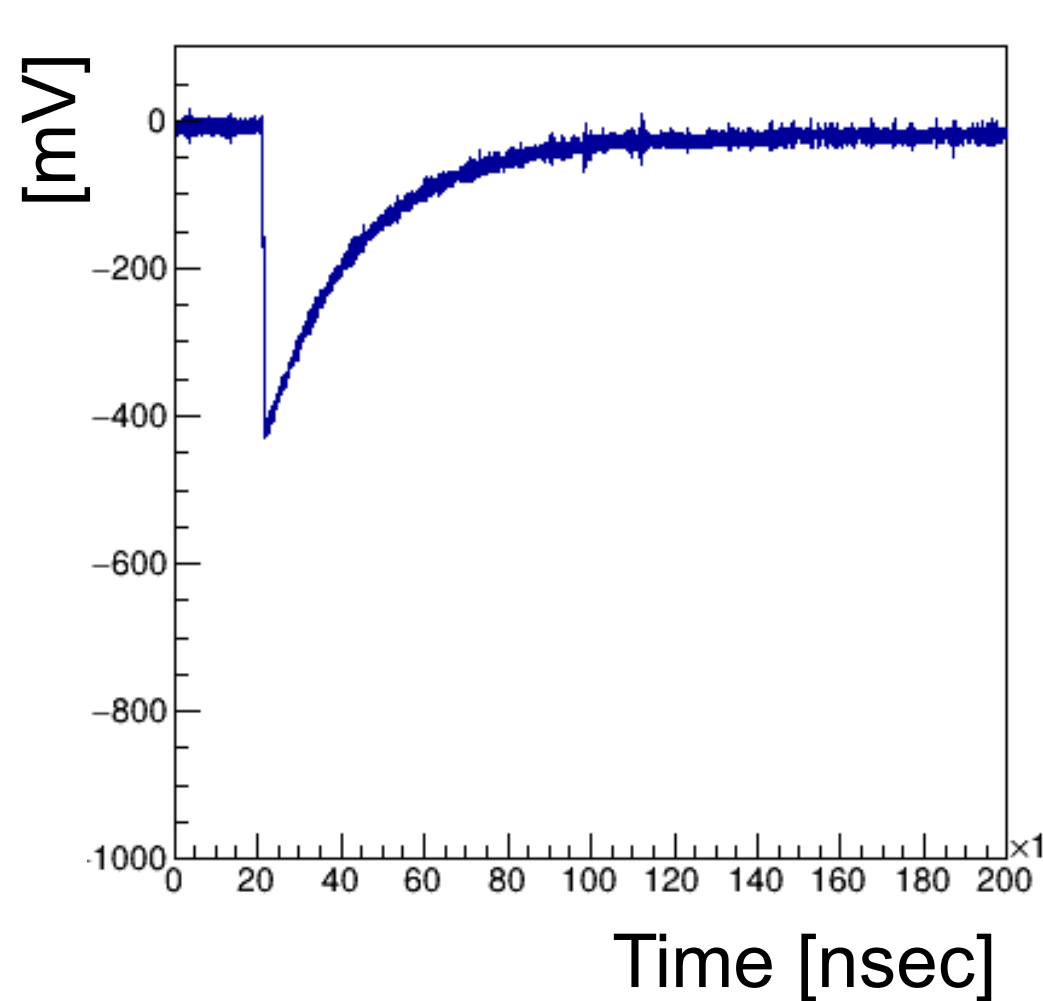
## Beam Test at MLF

**Goal:** Check the performance with a pulsed muon beam

- Pulse height for a single incident muon → **Detector response**
- Correlation of the number of incident muons and pulse height → **Linearity**

→ **Beam test was performed at MLF D2 line in June 2024.**

### Typical Waveform from SiC Detector (40 MeV/c)

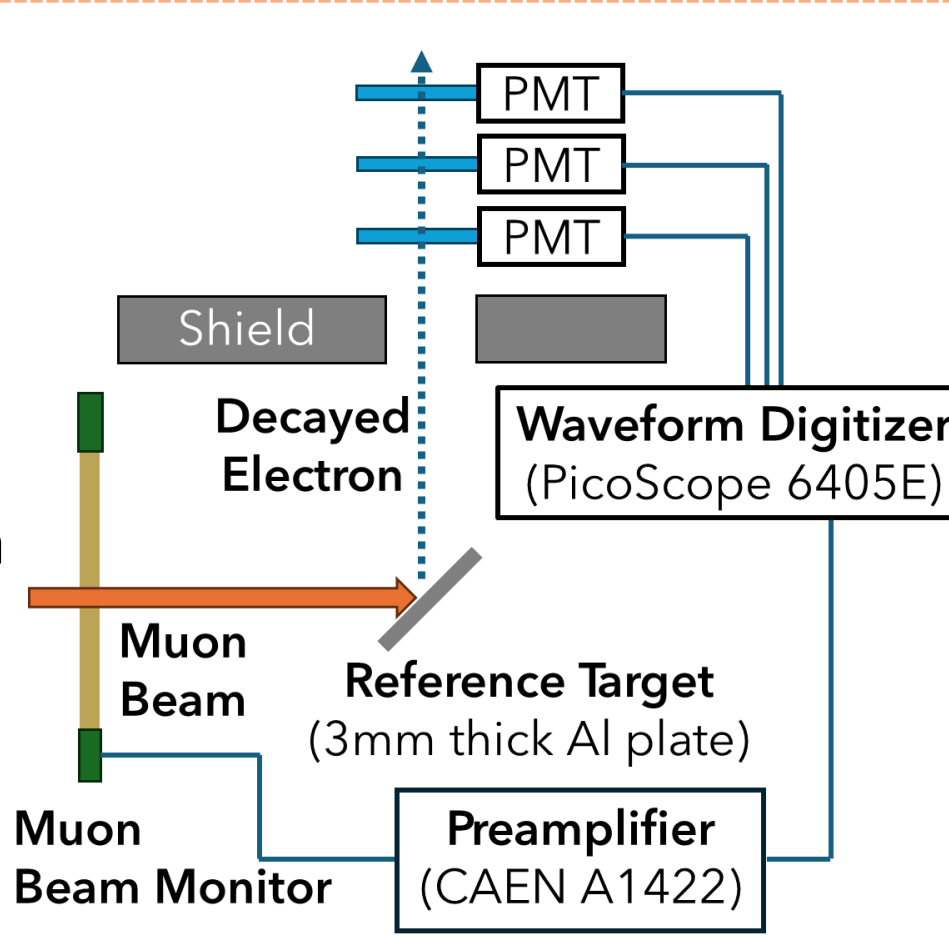


### Beam Test Setup

- Read out by commercial preamplifier (1 V / pC, 27 μs time constant).
- Read out one chip at a time.
- Triggered in synchronization with the accelerator's injection timing.

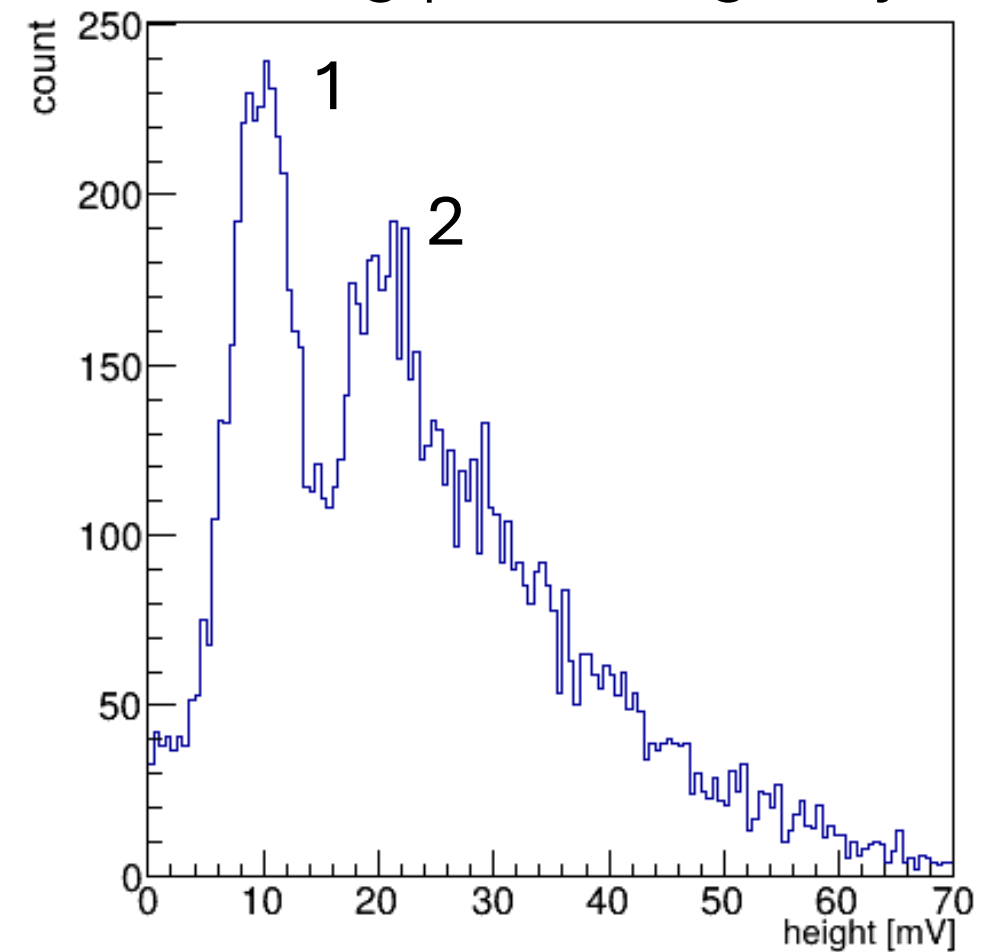
### MLF D2 Beamline

- Momentum: 20 ~ 100 MeV/c ( $\mu^+$ )
- Pulsed muon beam (25 Hz, ~ 20 muons / sensor / bunch)



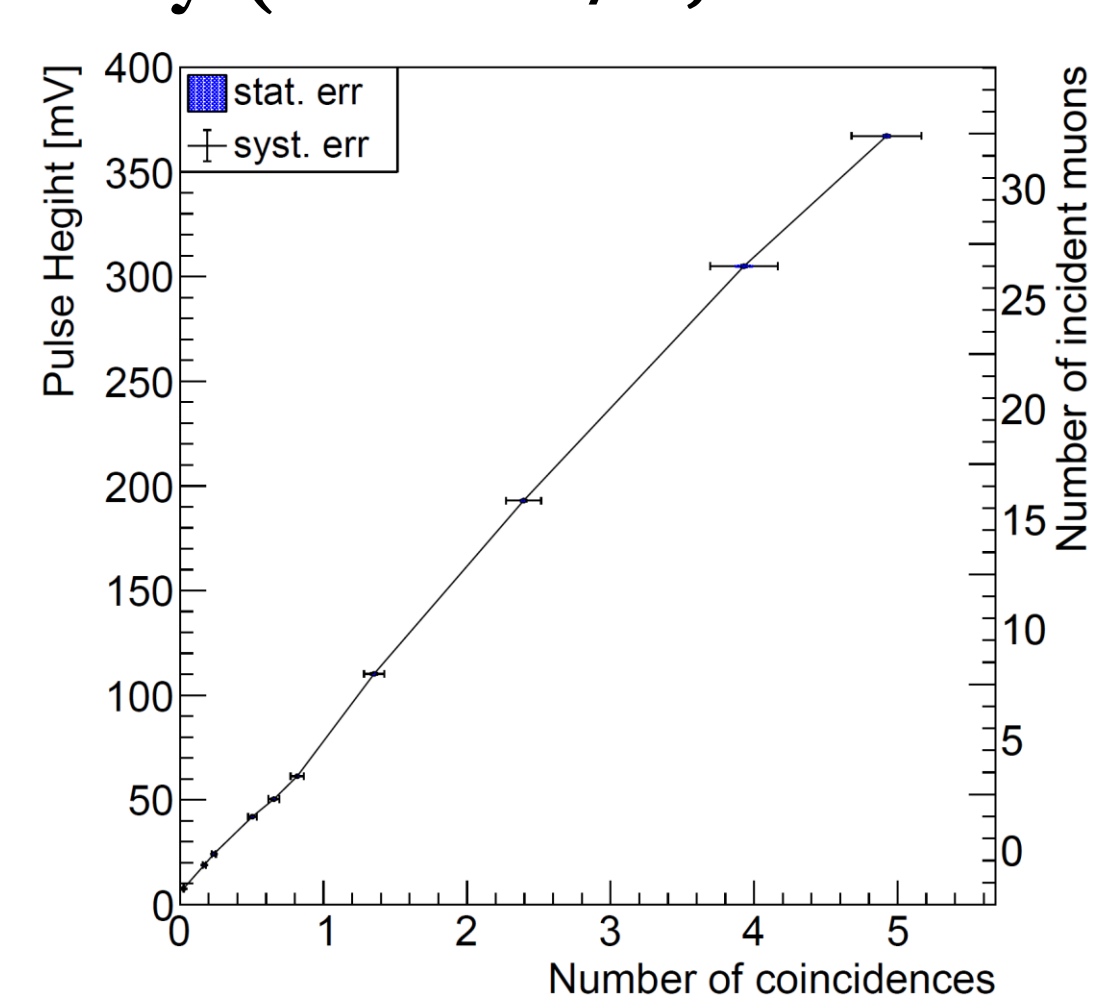
### Pulse Height Distribution

- Determining pulse height by fitting.



- Clearly seen 1 or 2 muons peaks

### Linearity (40 MeV/c, 1000 V HV)



- Sufficient linearity was confirmed up to approximately **35 incident muons**.

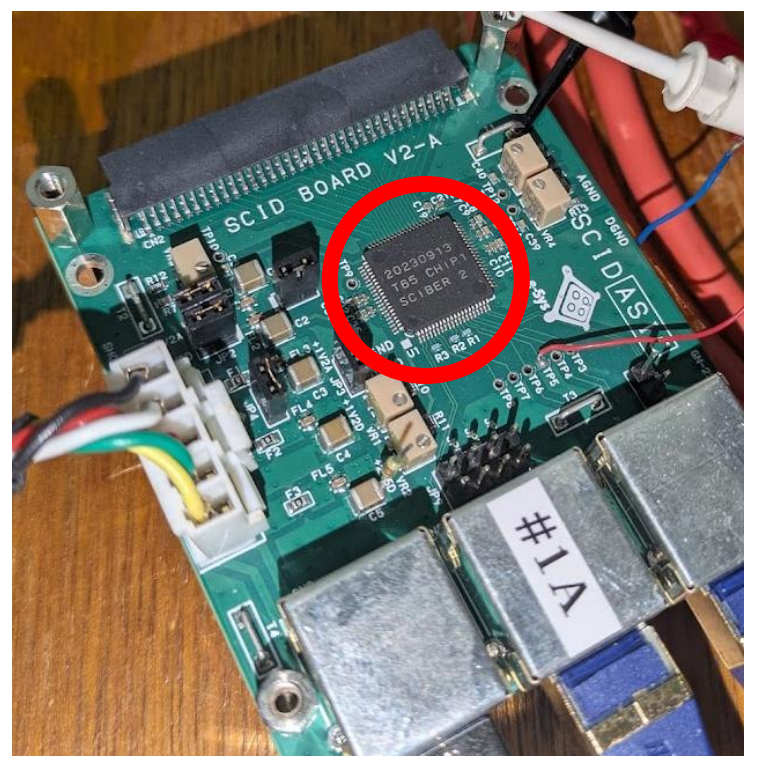
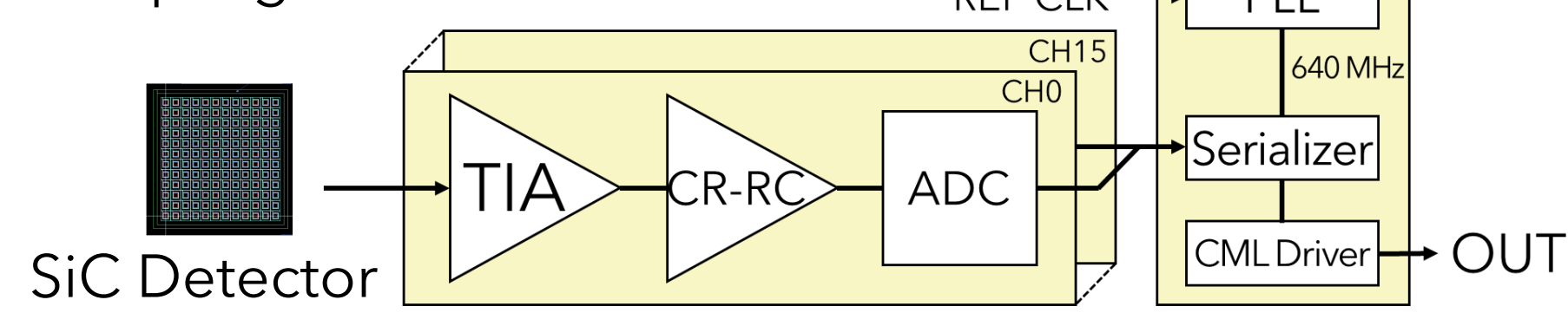
## Readout ASIC

### - SCIBER (Silicon Carbide readout IC for muon-BEam monitoR)

- ASIC will be used for readout electronics of the SiC detector.
- The second prototype had already been developed by KEK.**

### Specifications

- Consists of 16 channels per chip.
- Each channel consists of trans-impedance amplifier, CR-RC bandpass filter, and 8bit SAR ADC with 10 MHz sampling clock.



Readout board with SCIBER2 ASIC

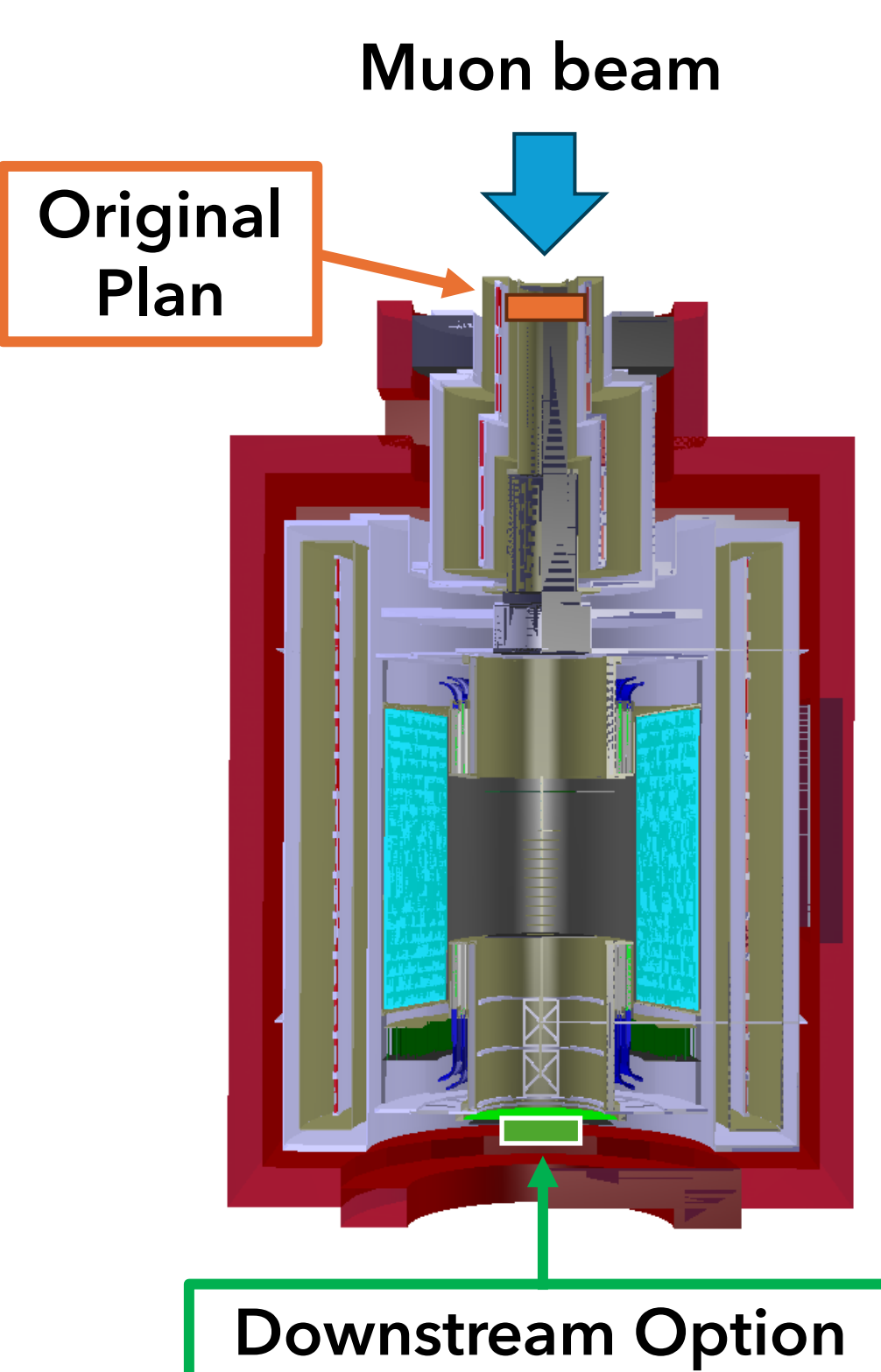
## Installation Plan

### Original: Upstream

- Installing at the transport solenoid exit
- Sufficient pulse height (~57 muons / chip(centre) / bunch)
- Small beam size, small detector size
- High radiation level
- Hard to access the beam monitor system
- Reduced muon yield

### Option: Downstream

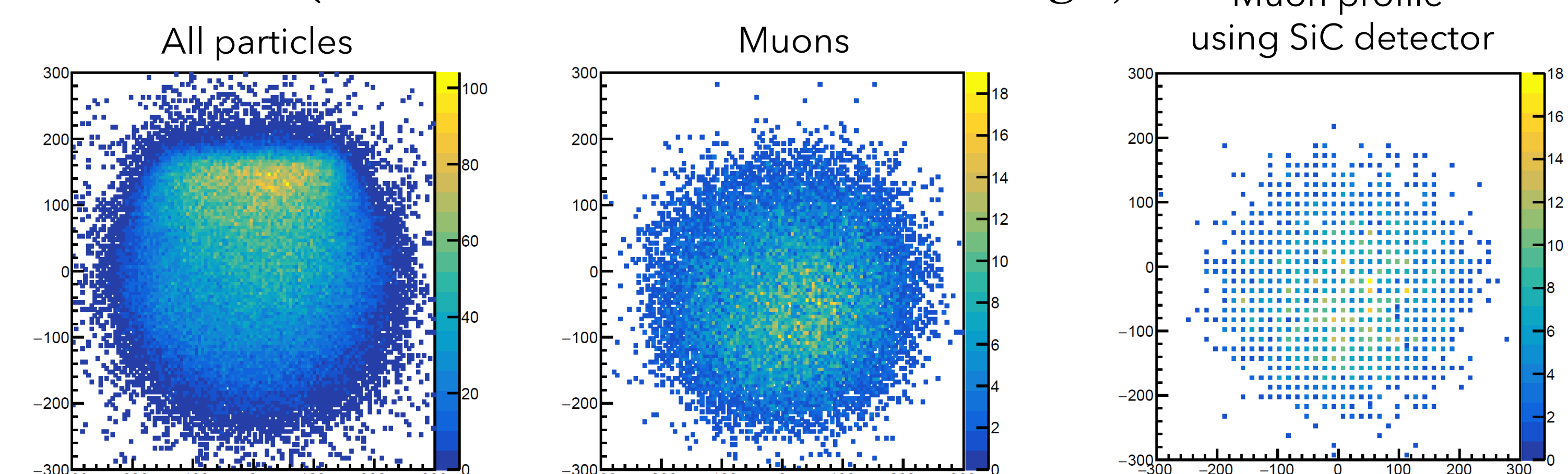
- Installing downstream of the primary detector system
- Low radiation level
- Easy to access the beam monitor system
- Does not affect the muon yield
- Smaller pulse height, worse S/N (~16 muons / chip(centre) / bunch)
- Larger beam size, larger detector size (twice the size)



## Simulation Study of Downstream Installation

Investigation of muon beam profile and expected waveform using Geant4 based simulation framework for COMET Experiment.

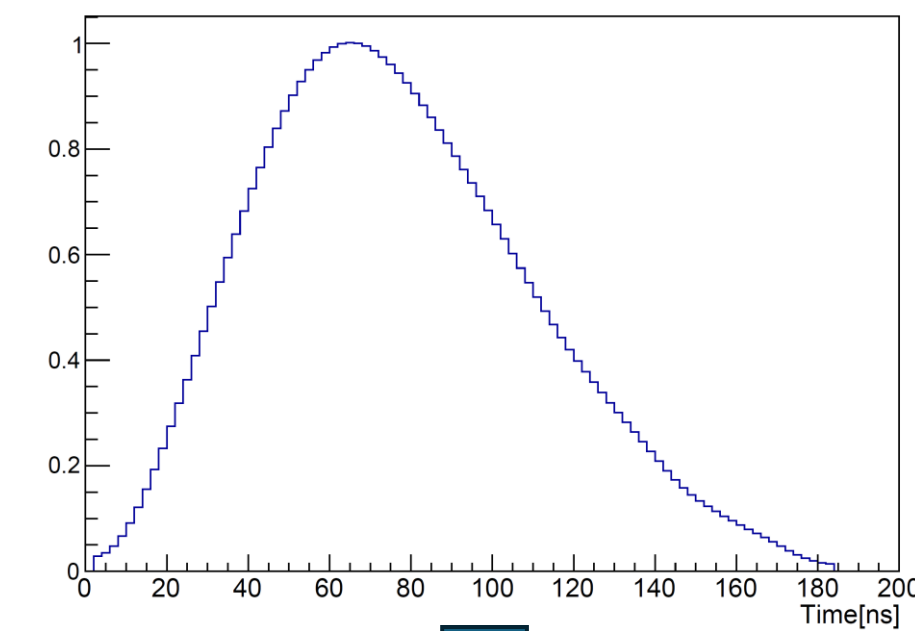
### Beam Profile (1 bunch = $1.6 \times 10^7$ Protons on target)



→ 16 muons will incident on center SiC detector chip

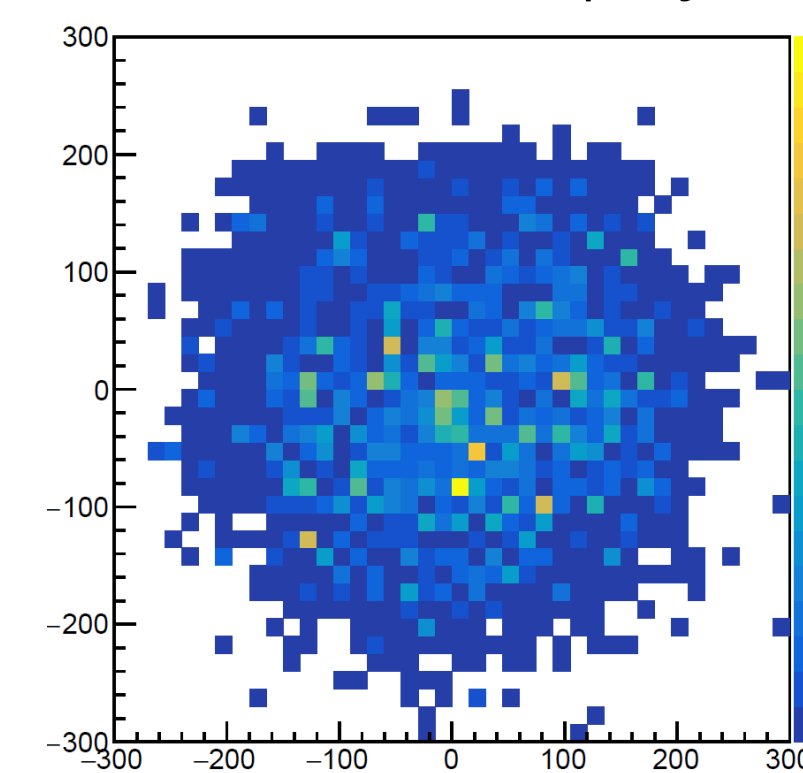
### Expected waveform and beam profile monitor

#### Simulated ASIC waveform

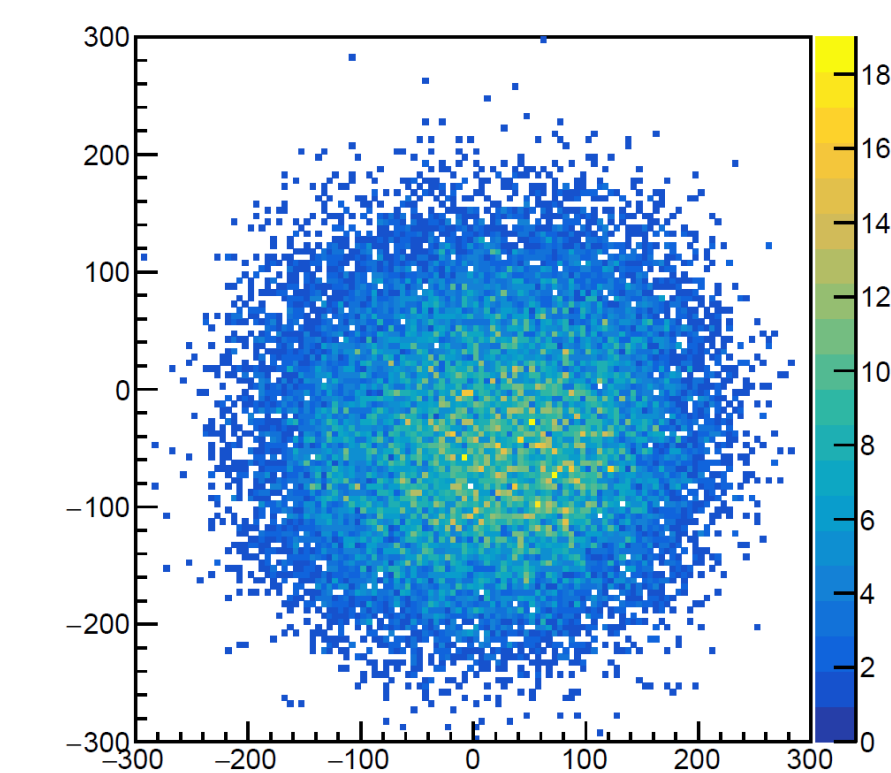


#### Sampling waveform at 260 ns

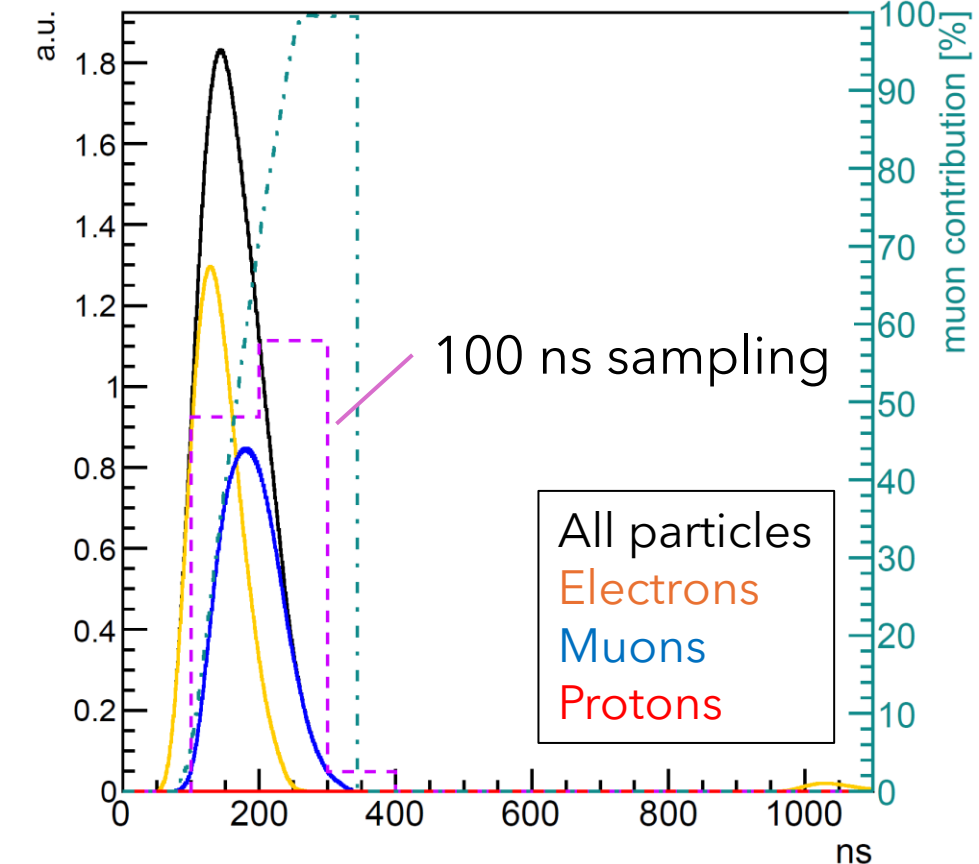
#### Monitor Display



#### Muon profile

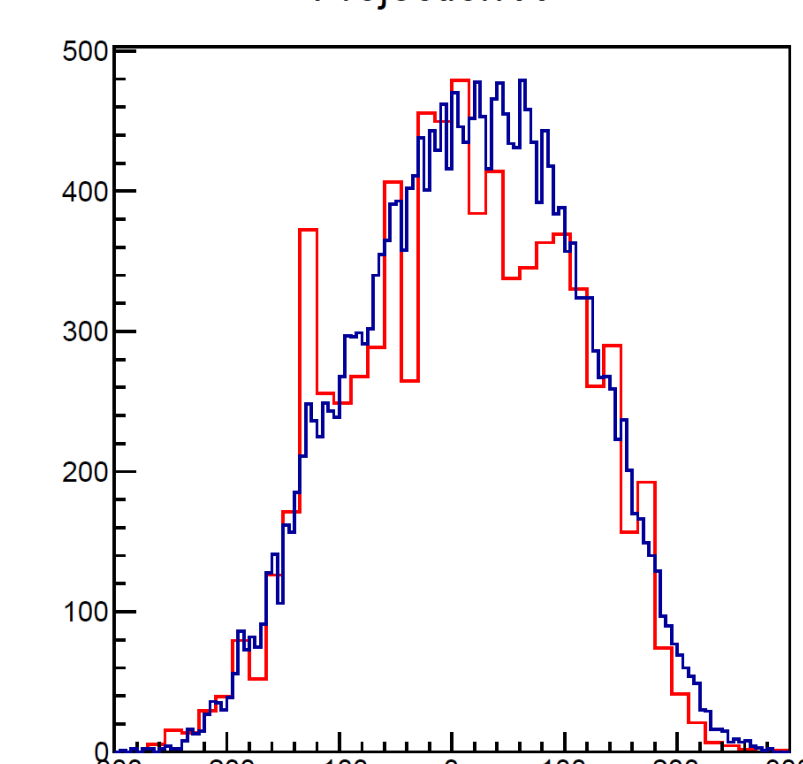


#### Expected waveform from SiC detector (centre)

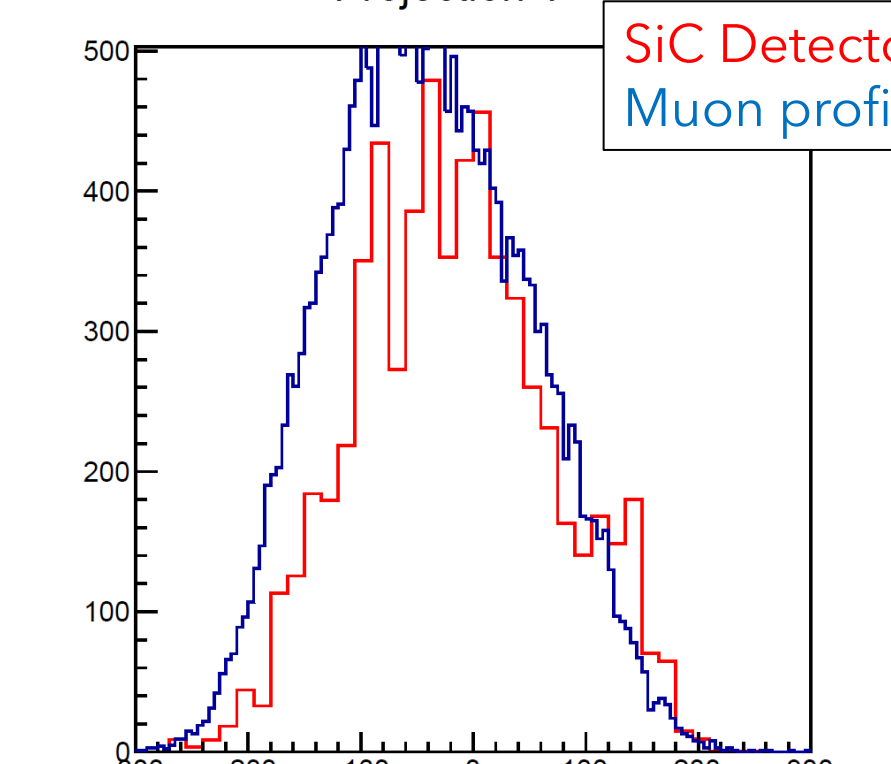


→ Muon contribution dominates within 200 ~ 300 ns

#### Projection X



#### Projection Y



→ By sampling the waveform at this timing, the muon profile can be roughly reproduced.

## Summary

- A beam test was performed to check the performance of SiC detector, confirming sufficient linearity up to around 35 incident muons.
- Simulation study of downstream installation option revealed that approximately 16 muons are incident on center chip, and the output waveform is dominated by muons in the range of 200~300 ns.
- Determining the installation location and producing the monitor board for Phase-I. Evaluation of the next prototype ASIC will be conducted, followed by the production of the final version, aiming for the overall system completion.